National Semiconductor

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DM54194
4-Bit Bidirectional Universal Shift Registers

General Description

This bidirectional shift register is designed to incorporate virtually all of the features a system designer may want in a shift register; it features parallel inputs, parallel outputs, right-shift and left-shift serial inputs, operating-mode-control inputs, and a direct overriding clear line. The register has four distinct modes of operation, namely:

Parallel (broadside) load
Shift right (in the direction Q_A toward Q_D)
Shift left (in the direction Q_D toward Q_A)
Inhibit clock (do nothing)

Synchronous parallel loading is accomplished by applying the four bits of data and taking both mode control inputs, S0 and S1, high. The data is loaded into the associated flip-flops and appears at the outputs after the positive transition of the clock input. During loading, serial data flow is inhibited.

Shift right is accomplished synchronously with the rising edge of the clock pulse when S0 is high and S1 is low. Serial data for this mode is entered at the shift-right data input. When S0 is low and S1 is high, data shifts left synchronously and new data is entered at the shift-left serial input.

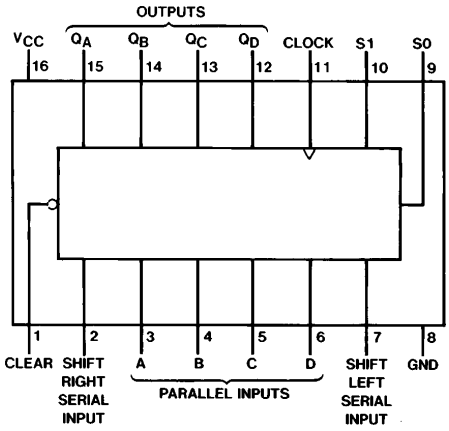
Clocking of the flip-flop is inhibited when both mode control inputs are low. The mode controls of the DM54194/DM74194 should be changed only while the clock input is high.

Features

- Parallel inputs and outputs
- Four operating modes:
  - Synchronous parallel load
  - Right shift
  - Left shift
  - Do nothing
- Positive edge-triggered clocking
- Direct overriding clear
- Typical clock frequency 36 MHz
- Typical power dissipation 195 mW

Connection Diagram

Dual-In-Line Package



TL/F/6564–1

Order Number DM54194J or DM54194W
See NS Package Number J16A or W16A

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter		DM54194			Units
			Min	Nom	Max	
V_{CC}	Supply Voltage		4.5	5	5.5	V
V_{IH}	High Level Input Voltage		2			V
V_{IL}	Low Level Input Voltage				0.8	V
I_{OH}	High Level Output Current				−0.8	mA
I_{OL}	Low Level Output Current				16	mA
f_{CLK}	Clock Frequency (Note 4)		0	36	25	MHz
t_W	Pulse Width (Note 4)	Clock	20			ns
		Clear	20			
t_{SU}	Setup Time (Note 4)	Mode	30			ns
		Data	20			
t_H	Hold Time (Note 4)		0			ns
t_{REL}	Clear Release Time (Note 4)		25			ns
T_A	Free Air Operating Temperature		−55		125	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −12 mA			−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max V_{IL} = Max, V_{IH} = Min	2.4	3.4		V
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max V_{IH} = Min, V_{IL} = Max		0.2	0.4	V
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 5.5V			1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.4V			40	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V			−1.6	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 2)	−20		−57	mA
I_{CC}	Supply Current	V_{CC} = Max (Note 3)		39	63	mA

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time.

Note 3: With all outputs open, inputs A through D grounded, and 4.5V applied to S0, S1, CLEAR and the serial inputs, I_{CC} is tested with a momentary ground, then 4.5V applied to CLOCK.

Note 4: T_A = 25°C and V_{CC} = 5V.

Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	From (Input) To (Output)	R_L = 400Ω, C_L = 15 pF		Units
			Min	Max	
f_{MAX}	Maximum Clock Frequency		25		MHz
t_{PLH}	Propagation Delay Time Low to High Level Output	Clock to Q		22	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clock to Q		26	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	Clear to Q		30	ns

Function Table

Inputs										Outputs			
Clear	Mode		Clock	Serial		Parallel				Q_A	Q_B	Q_C	Q_D
	S1	S0		Left	Right	A	B	C	D				
L	X	X	X	X	X	X	X	X	X	L	L	L	L
H	X	X	L	X	X	X	X	X	X	Q_{A0}	Q_{B0}	Q_{C0}	Q_{D0}
H	H	H	↑	X	X	a	b	c	d	a	b	c	d
H	L	H	↑	X	H	X	X	X	X	H	Q_{An}	Q_{Bn}	Q_{Cn}
H	L	H	↑	X	L	X	X	X	X	L	Q_{An}	Q_{Bn}	Q_{Cn}
H	H	L	↑	H	X	X	X	X	X	Q_{Bn}	Q_{Cn}	Q_{Dn}	H
H	H	L	↑	L	X	X	X	X	X	Q_{Bn}	Q_{Cn}	Q_{Dn}	L
H	L	L	X	X	X	X	X	X	X	Q_{A0}	Q_{B0}	Q_{C0}	Q_{D0}

H = High Level (steady state), L = Low Level (steady state), X = Don't Care (any input, including transitions)

↑ = Transition from low to high level; a, b, c, d = The level of steady state input at inputs A, B, C, or D, respectively

Q_{A0}, Q_{B0}, Q_{C0}, Q_{D0} = The level of Q_A, Q_B, Q_C, or Q_D, respectively, before the indicated steady state input conditions were established.

Q_{An}, Q_{Bn}, Q_{Cn}, Q_{Dn} = The level of Q_A, Q_B, Q_C, respectively, before the most recent ↑ transition of the clock.

Logic Diagram

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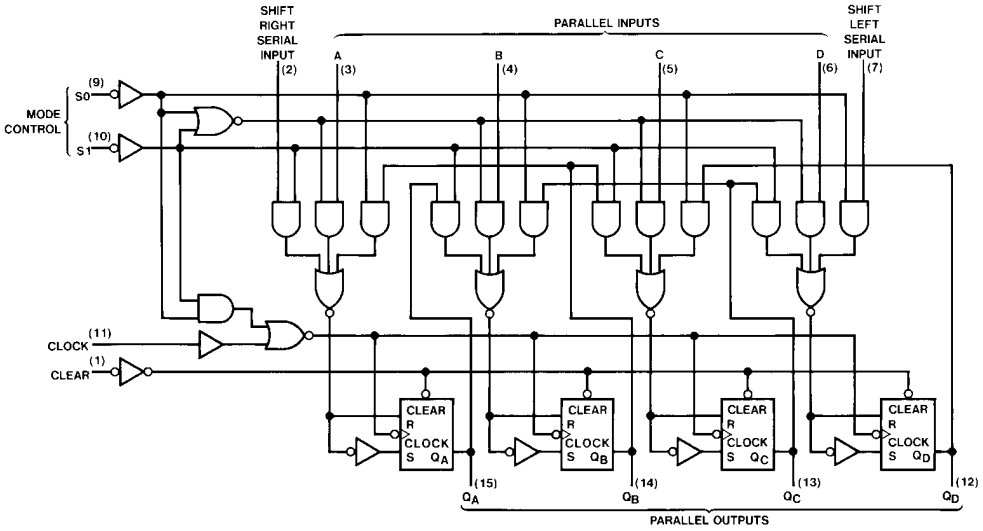

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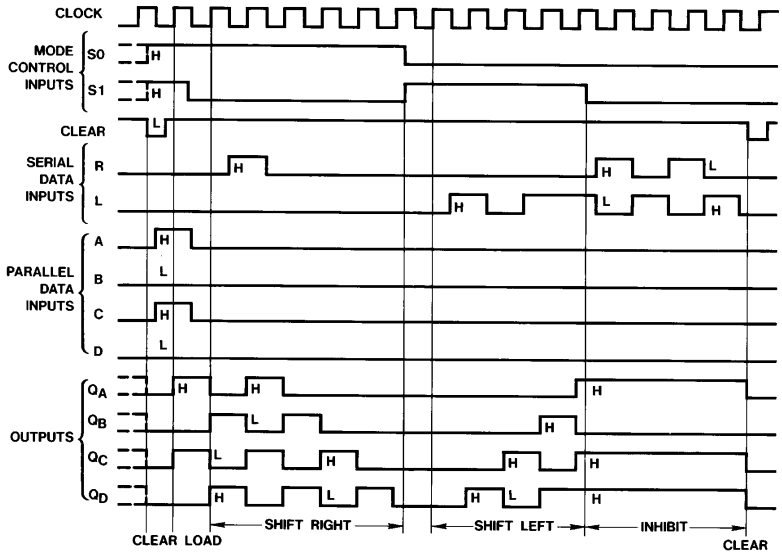
Timing Diagram

Typical Clear, Load, Right-Shift, Left-Shift, Inhibit and Clear Sequences



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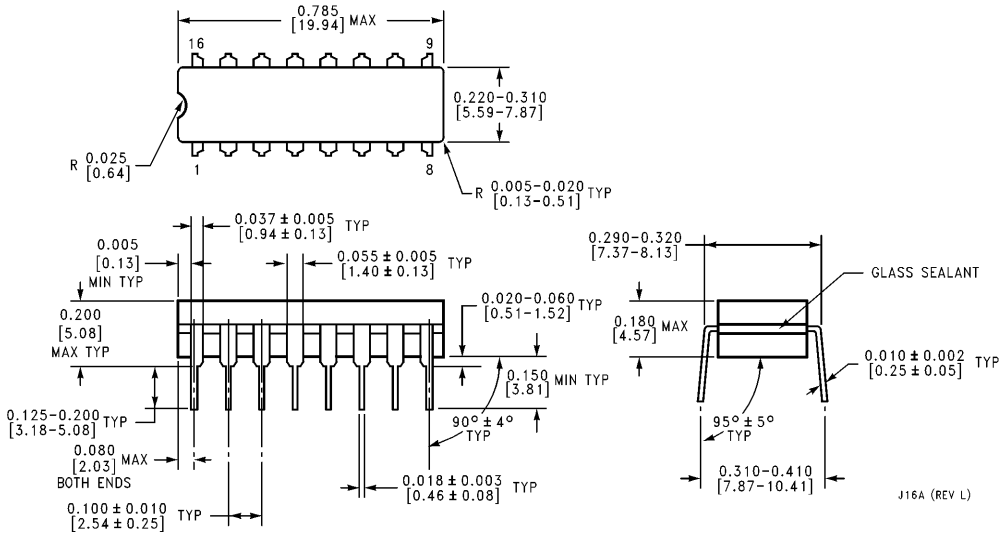
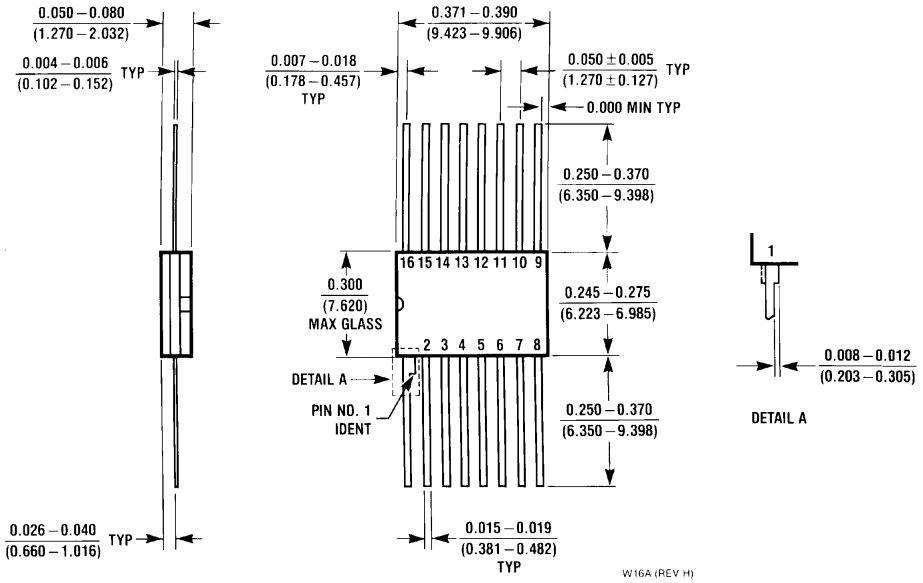
Physical Dimensions inches (millimeters)



16-Lead Ceramic Dual-In-Line Package (J)
Order Number DM54194J
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)



16-Lead Ceramic Flat Package (W)
Order Number DM54194W
NS Package Number W16A

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National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408